Triple Inverter

The NL37WZ04 is a high performance triple inverter operating from a 1.65 V to 5.5 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance.

Features

- Extremely High Speed: t_{PD} 2.0 ns (typical) at V_{CC} = 5 V
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTL Compatible Interface Capability With 5 V TTL Logic with V_{CC} = 3 V
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72
- These Devices are Pb-Free and are RoHS Compliant

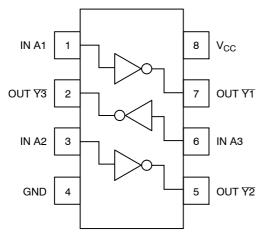
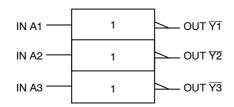


Figure 1. Pinout (Top View)

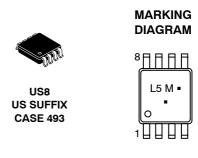






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L5 = Device Code M = Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

PIN ASSIGNMENT				
Pin	Function			
1	IN A1			
2	OUT <u>Y3</u>			
3	IN A2			
4	GND			
5	OUT Y2			
6	IN A3			
7	OUT <u>Y1</u>			
8	V _{CC}			

FUNCTION TABLE

A Input	 Y Output
L	Н
Н	L

ORDERING INFORMATION

Dev	vice	Package	Shipping [†]
NL37WZ	Z04USG	US8 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Symbol	Parameter	Value	Units
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage	-0.5 to +7.0	V
Ι _{ΙΚ}	DC Input Diode Current V _I < GND	-50	mA
Ι _{ΟΚ}	DC Output Diode Current $V_0 < GND$	-50	mA
Ι _Ο	DC Output Sink Current	±50	mA
I _{CC}	DC Supply Current per Supply Pin	±100	mA
I _{GND}	DC Ground Current per Ground Pin	±100	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
Τ _J	Junction Temperature under Bias	+150	°C
θ_{JA}	Thermal Resistance (Note 1)	250	°C/W
PD	Power Dissipation in Still Air at 85°C	250	mW
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
 Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Units
V _{CC}	Supply Voltage Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage (Note 5)	0	5.5	V
Vo	Output Voltage (HIGH or LOW State)		5.5	V
T _A	Operating Free-Air Temperature		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate $V_{CC} = 2.5 V \pm 0.2 V$ $V_{CC} = 3.0 V \pm 0.3 V$ $V_{CC} = 5.0 V \pm 0.5 V$	0 0 0	20 10 5	ns/V

5. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

	Parameter	Condition	V _{CC} (V)	T _A = 25°C			–40°C ≤ T _A ≤ 85°C		
Symbol				Min	Тур	Max	Min	Max	Units
VIH	High-Level Input		1.65	0.75 V _{CC}			0.75 V _{CC}		V
	Voltage		2.3 to 5.5	0.7 V _{CC}			0.7 V _{CC}		
V _{IL}	Low-Level Input		1.65			0.25 V _{CC}		0.25 V _{CC}	V
	Voltage		2.3 to 5.5			0.3 V _{CC}		0.3 V _{CC}	
V _{OH}	High-Level Output	I _{OH} = -100 μA	1.65 to 5.5	V _{CC} -0.1	V _{CC}		V _{CC} -0.1		V
	Voltage V _{IN} = V _{IL}	I _{OH} = -3 mA	1.65	1.29	1.52		1.29		
		I _{OH} = -8 mA	2.3	1.9	2.1		1.9		
		I _{OH} = -12 mA	2.7	2.2	2.4		2.2		-
		I _{OH} = -16 mA	3.0	2.4	2.7		2.4		
		I _{OH} = -24 mA	3.0	2.3	2.5		2.3		
		I _{OH} = -32 mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH}	I _{OL} = 100 μA	1.65 to 5.5			0.1		0.1	V
		I _{OL} = 3 mA	1.65		0.08	0.24		0.24	
		I _{OL} = 8 mA	2.3		0.20	0.3		0.3	
		I _{OL} = 12 mA	2.7		0.22	0.4		0.4	
		I _{OL} = 16 mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24 mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Cur- rent	V _{IN} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0			1		10	μA
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5 V or GND	5.5			1		10	μA

AC ELECTRICAL CHARACTERISTICS t_R = t_F = 2.5 ns; C_L = 50 pF; R_L = 500 Ω

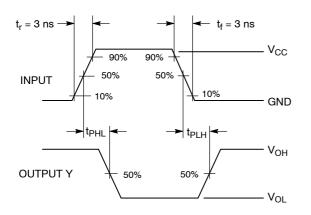
			V _{cc}	T _A = 25°C		–40°C ≤ T _A ≤ 85°C			
Symbol	Parameter	Condition	(Ň)	Min	Тур	Max	Min	Max	Units
t _{PLH}		$R_L = 1 M\Omega$, $C_L = 15 pF$	1.8 ± 0.15	1.8	4.4	9.5	2.0	10	ns
t _{PHL}	(Figure 3 and 4)	$R_L = 1 M\Omega$, $C_L = 15 pF$	2.5 ± 0.2	1.2	5.0	5.7	1.2	6.1	
		R_L = 1 MΩ, C_L = 15 pF R_L = 500 Ω, C_L = 50 pF	$\textbf{3.3}\pm\textbf{0.3}$	0.8 1.2	2.2 3.9	3.4 4.5	0.8 1.2	3.8 5.0	
		$ \begin{array}{l} R_{L} = 1 \ M\Omega, \ C_{L} = 15 \ pF \\ R_{L} = 500 \ \Omega, \ C_{L} = 50 \ pF \end{array} $	5.0 ± 0.5	0.5 0.8	1.8 2.3	2.8 3.6	0.5 0.8	3.1 4.0	

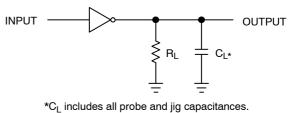
CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Parameter Condition		Units
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 6)	10 MHz, V_{CC} = 3.3 V, V_I = 0 V or V_{CC} 10 MHz, V_{CC} = 5.5 V, V_I = 0 V or V_{CC}	9 11	pF

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

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A 1–MHz square input wave is recommended for propagation delay tests.

Figure 3. Switching Waveform

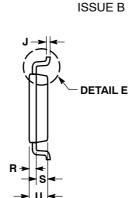


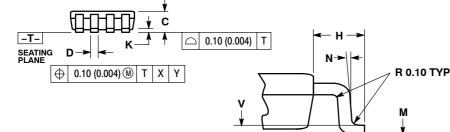
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PACKAGE DIMENSIONS

US8 CASE 493-02

-Xв \mathbf{C} G Р





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DETAIL E

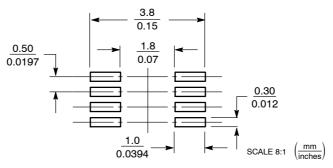
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE DUDD DUALL NOT EXCEPT ON AND GATE
- BURR SHALL NOT EXCEED 0.140 MM (0.0055") PER SIDE.
- IMENSION "B" DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSION. INTER-LEAD FLASH AND PROTRUSION 4. SHALL NOT E3XCEED 0.140 (0.0055") PER SIDE
- LEAD FINISH IS SOLDER PLATING WITH 5. THICKNESS OF 0.0076-0.0203 MM.
- (300-800 °). ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 (0.0002 °). 6.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	1.90	2.10	0.075	0.083	
В	2.20	2.40	0.087	0.094	
С	0.60	0.90	0.024	0.035	
D	0.17	0.25	0.007	0.010	
F	0.20	0.35	0.008	0.014	
G	0.50	BSC	0.020	BSC	
н	0.40	REF	0.016 REF		
J	0.10	0.18	0.004	0.007	
ĸ	0.00	0.10	0.000	0.004	
L	3.00	3.20	0.118	0.126	
M	0 °	6 °	0 °	6 °	
N	5 °	10 °	5 °	10 °	
P	0.23	0.34	0.010	0.013	
R	0.23	0.33	0.009	0.013	
S	0.37	0.47	0.015	0.019	
U	0.60	0.80	0.024	0.031	
V	0.12	BSC	0.005 BSC		

SOLDERING FOOTPRINT*

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*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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